COMPLIANT

Vishay Siliconix

0.37 Ω , Low Capacitance, Dual DPDT / Quad SPDT Analog Switch

DESCRIPTION

The DG2788A, is a four-channel single-pole double-throw (SPDT) analog switch with two control inputs. It is also known as a two-channel double-pole double-throw (DPDT) configuration. The part is designed to operate from 1.8 V to 5.5 V single power rail. All switches conduct equally well in both directions, offering rail to rail signal witching and can be used both as multiplexers as well as de-multiplexers.

The DG2788A offers low parasitic capacitance and highly matched low and flat switch resistance over the full signal range. It features break-before-make switching and low control logic threshold. The part supports rail to rail fast edge pulsing signals and have 0.1 ns/typ. propagation delay. It is ideal for both analog and digital signal switching in space constrain applications requiring high performance and efficient use of board space.

The DG2788A comes in a small miniQFN-16 lead package of 2.6 mm x 1.8 mm x 0.55 mm.

FEATURES

- 1.8 V to 5.5 V single supply operation
- Low resistance: 0.37 Ω/typ. at 2.7 V
- Highly flat and matched R_{ON}
- Low parasitic capacitance,
 C_{ON} = 26 pF, C_{OFF} = 14.5 pF
- High bandwidth: 338 MHz
- 0.1 ns/typ. propagation delay for rail to rail fast edge pulsing signal
- Guaranteed logic high 1.2 V, logic low 0.3 V
- Break before make switching
- Signal swing over V+ capable
- Power down protection
- Latch up current: 300 mA (JESD78)
- ESD / HBM: > 2 kV
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

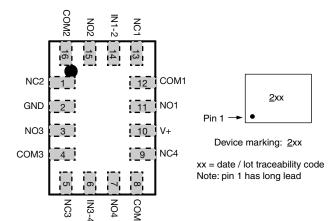
BENEFITS

- · Low and flat resistance
- · Excellent total harmonic distortion
- · Low parasitic capacitance
- Low voltage control interface

APPLICATIONS

- · Analog and digital signal switching
- SMA optical image stabilization
- Relay replacement
- Portable instrumentation
- Smart phones and tablets
- Modems and peripherals
- · Data storage

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



S16-1836-Rev. B, 12-Sep-16

TRUTH TABLE					
LOGIC	NC1, 2, 3 and 4	NO1, 2, 3 and 4			
0	On	Off			
1	Off	On			



www.vishay.com

Vishay Siliconix

ORDERING INFORMATION						
TEMPERATURE RANGE	PACKAGE	PART NUMBER	MIN. ORDER / PACK. QUANTITY			
-40 °C to +85 °C lead (Pb)-free	miniQFN-16	DG2788ADN-T1-GE4	Tape and reel, 3000 units			

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Reference to GND	V+		-0.3 to +6	V		
Reference to GND	IN, COM, NC, NO a		-0.3 to (V+ + 0.3)	¬		
Current (any terminal except NO, NC, or	COM)		30			
Continuous current (NO, NC, or COM)			± 300	mA		
Peak current (pulsed at 1 ms, 10 % duty	cycle)		± 500			
Storage temperature (D suffix)			-65 to +150			
Package solder reflow conditions d	miniQFN-16		250	°C		
Power dissipation (packages) ^b	miniQFN-16 ^c		525	mW		

Notes

- a. Signals on NC, NO, or COM, or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6.6 mW/°C above 70 °C.
- d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS unless otherwise specified	TEMP.a	LIMITS -40 °C to +85 °C			UNIT
		$V+ = 3 V, \pm 10 \%, V_{IN} = 0.5 \text{ or } 1.4 \text{ V} ^{\text{e}}$		MIN. b	TYP. c	MAX. b	
Analog Switch							
Analog signal range d	V_{NO}, V_{NC}, V_{COM}		Full	0	-	V+	V
On-resistance	R _{ON}	$V+ = 2.7 \text{ V}, V_{COM} = 0 \text{ to } 2.7 \text{ V}, I_{NO}, I_{NC} = 100 \text{ mA}$	Room	-	0.37	0.5	
On-resistance	TION		Full	-	-	0.6	
R _{ON} flatness ^d	R _{ON} flatness	$V+ = 2.7 \text{ V}, V_{COM} = 0 \text{ to V+}, \\ I_{NO}, I_{NC} = 100 \text{ mA}$	Room	ı	0.01	0.05	Ω
R _{ON} match ^d	ΔR_{ON}	1NO, INC = 100 IIIA	Room	ı	0.05	-	
	I _{NO(off)} ,		Room	-0.1	-	0.1	
Switch off lookage current	I _{NC(off)}	$V+ = 5.5 \text{ V}, V_{NO}, V_{NC} = 0.5 \text{ V} / 4 \text{ V},$	Full	-0.5	-	0.5	l
Switch off leakage current	ı	$V_{COM} = 4 \text{ V} / 0.5 \text{ V}$	Room	-1.2	-	1.2	
	ICOM(off)		Full	-2	-	2	μA
Channel-on leakage		V: -55VV V -V -05V/4V	Room	-1.2	-	1.2	
current	I _{COM(on)}	$V+ = 5.5 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.5 \text{ V} / 4 \text{ V}$	Full	-2	-	2	
Digital Control							
Input high voltage	V _{INH}		Full	1.2	-	-	V
Input low voltage	V _{INL}		Full	-	-	0.3	V
Input capacitance	C _{IN}		Full	-	5	-	pF
Input current	I _{INL} or I _{INH}	$V_{IN} = 0$ or V+	Full	-1	-	1	μΑ
Dynamic Characteristics							
Turn-on time	t _{ON}		Room	ı	30	50	μs
rum-on ume		V_{NO} or $V_{NC} = 1.5 \text{ V}$, $R_1 = 50 \Omega$, $C_1 = 35 \text{ pF}$	Full	-	-	150	
Turn-off time	t _{OFF}	$v_{NO} \text{ or } v_{NC} = 1.5 \text{ v, } n_L = 50.22, G_L = 35 \text{ pr}$	Room	-	0.35	1	
rum-on time			Full	-	-	3	
Break-before-make time	t _d		Full	1	-	-	
Charge injection ^d	Q _{INJ}	C_L = 1 nF, V_{GEN} = 1.5 V, R_{GEN} = 0 Ω	Room	-	-245	-	рС
-3 dB bandwidth	BW	$R_L = 50 \Omega$, $C_L = 5 pF$	Room	-	338	-	MHz
Off-isolation d	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 100 kHz$		-	-82	-	dB
On-isolation •		$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$	D	-	-56	-	
Crosstalk d, f	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 100 kHz$	Room	-	-87	-	
Crosstalk 4,1		$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$		-	-61	-	
NO NO off conscitered	C _{NO(off)}		Room	-	14.5	-	
NO, NC off capacitance d	C _{NC(off)}		Room	-	14.5	-	pF
Channel-on capacitance d	C _{NO(on)}	f = 1 MHz	Room	-	26	-	
	C _{NC(on)}		Room	-	26	-	
Power Supply							
D	V+			1.8	_	5.5	V
Power supply range	V+			1.0	_	5.5	v

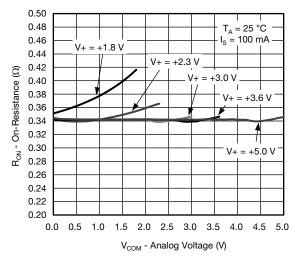
Notes

- a. Room = 25 °C, full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, not subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Crosstalk measured between channels.

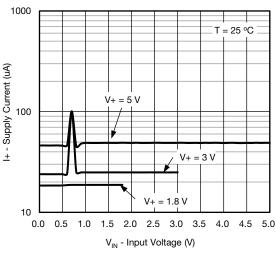
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



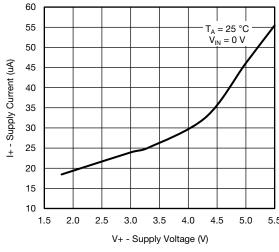
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



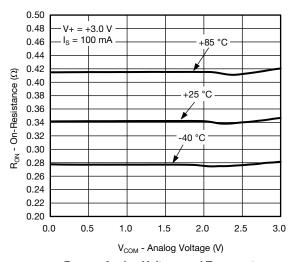
R_{ON} vs. V_{COM} and Supply Voltage



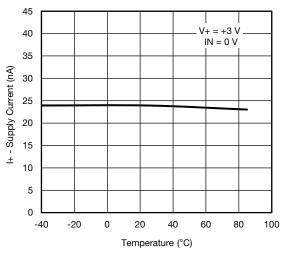
Supply Current vs. Input Voltage



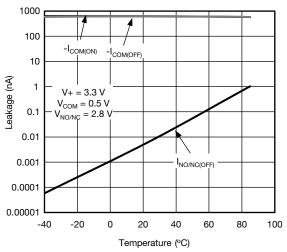
Supply Current vs. Supply Voltage



R_{ON} vs. Analog Voltage and Temperature



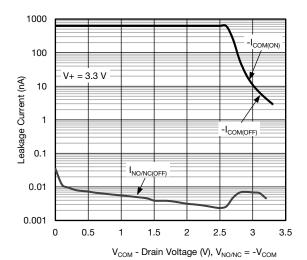
Supply Current vs. Temperature



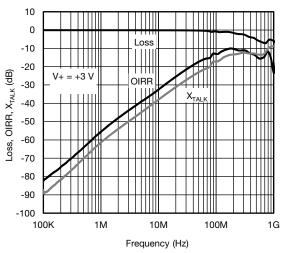
Leakage Current vs. Temperature



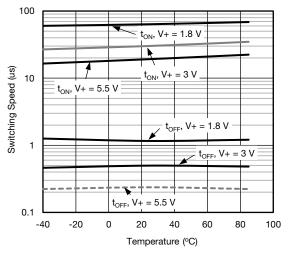
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



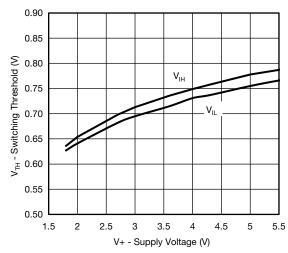
Leakage Current vs. Drain Voltage



Insertion Loss, Off-Isolation Crosstalk vs. Frequency



Switching Time vs. Temperature

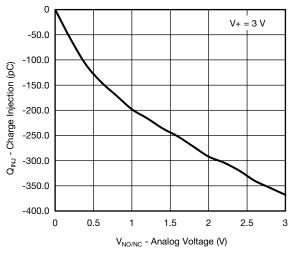


Switching Threshold vs. Supply Voltage

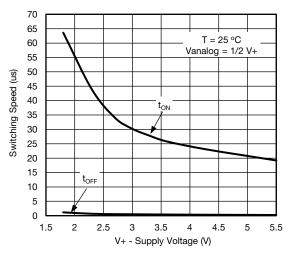
ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



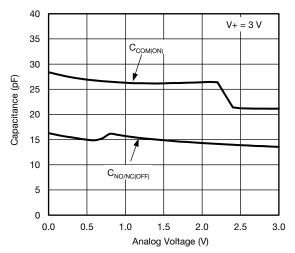
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Charge Injection vs. Analog Voltage



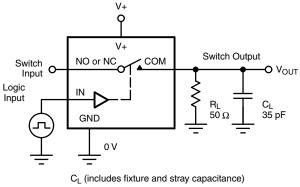
Switching Time vs. Supply Voltage



Capacitance vs. Analog Voltage



TEST CIRCUITS



 V_{INH} t_r < 5 ns Logic 50 % $t_f < 5 \text{ ns}$ Input V_{INL} 0.9 x V_{OUT} Switch Output 0 V t_{ON}

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

Fig. 1 - Switching Time

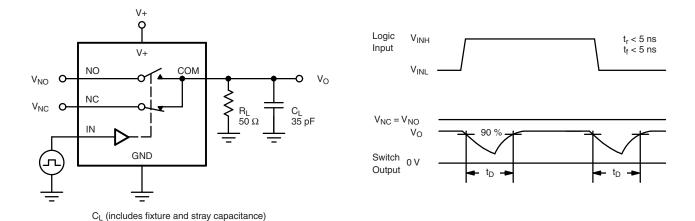


Fig. 2 - Break-Before-Make Interval

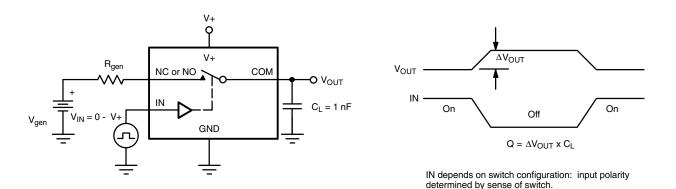
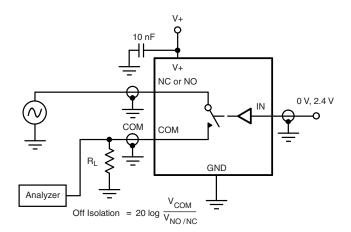
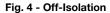


Fig. 3 - Charge Injection

Vishay Siliconix





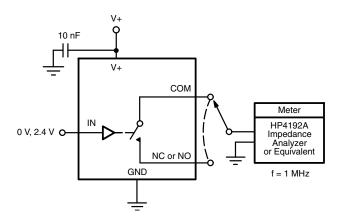
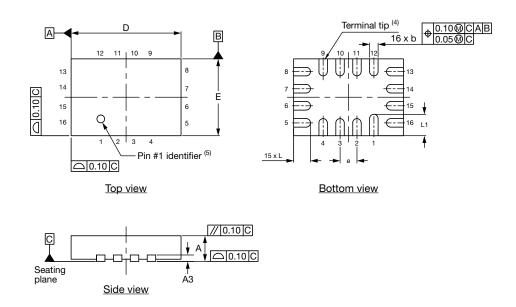


Fig. 5 - Channel Off / On Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg279391.



Thin miniQFN16 Case Outline



DIMENSIONS	MILLIMETERS (1)			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	0.50	0.55	0.60	0.020	0.022	0.024	
A1	0	-	0.05	0	-	0.002	
A3	0.15 ref.				0.006 ref.		
b	0.15	0.20	0.25	0.006	0.008	0.010	
D	2.50	2.60	2.70	0.098	0.102	0.106	
е	0.40 BSC			0.016 BSC			
Е	1.70	1.80	1.90	0.067	0.071	0.075	
L	0.35	0.40	0.45	0.014	0.016	0.018	
L1	0.45	0.50	0.55	0.018	0.020	0.022	
N (3)	16			16			
Nd ⁽³⁾	4			4			
Ne ⁽³⁾	4 4						

Notes

- (1) Use millimeters as the primary measurement.
- (2) Dimensioning and tolerances conform to ASME Y14.5M. 1994.
- (3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
- (4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
- (5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
- (6) Package warpage max. 0.05 mm.

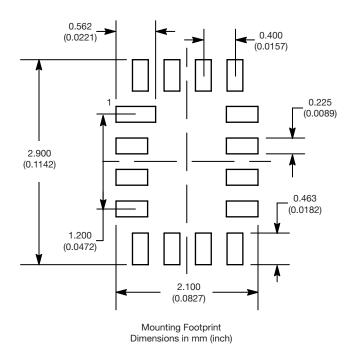
ECN: T16-0226-Rev. B, 09-May-16

DWG: 6023



Vishay Siliconix

RECOMMENDED MINIMUM PADS FOR MINI QFN 16L





Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.